THYRISTOR MODULE (NON-ISOLATED TYPE)

PWB100A



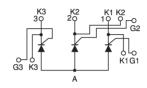


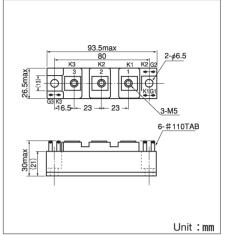


PWB100A is a Thyristor module suitable for low voltage, 3 phase recifier applications.

- IT(AV)100A (each device)
- High Surge Current 3500 A (60Hz)
- Easy Construction
- Non-isolated. Mounting base as common Anode terminal

(Applications)
Welding power Supply
Various DC power Supply





Maximum Ratings

Symbol	ltam	Ratings		Linit
	Item	PWB100A30	PWB100A40	Unit
V RRM	Repetitive Peak Reverse Voltage	300	400	V
VRSM	Non-Repetitive Peak Reverse Voltage	360	480	V
VDRM	Repetitive Peak Off-State Voltage	300	400	V

Symbol		Item	Conditions	Ratings	Unit
IT (AV)	Average On	-State Current	Single phase, half wave, 180° conduction, Tc: 114℃	100	Α
IT (RMS)	R.M.S. On-S	State Current	Single phase, half wave, 180° conduction, Tc: 114℃	157	Α
Ітѕм	Surge On-S	tate Current	½cycle, 50Hz/60Hz, peak value, non-repetitive	3200/3500	Α
l²t	l²t			51000	A ² S
Рам	Peak Gate Power Dissipation			10	W
Pg (AV)	Average Gate Power Dissipation			1	W
Iгдм	Peak Gate Current			3	Α
VFGM	Peak Gate Voltage (Forward)			10	V
VRGM	Peak Gate Voltage (Reverse)			5	V
di/dt	Critical Rate of Rise of On-State Current		Ig=200mA, Tj=25°C, VD= $\frac{1}{2}$ VDRM, dIg/dt=1A/ μ s	50	A/μs
Tj	Operating Junction Temperature			-30 ∼+150	°C
Tstg	Storage Temperature			-30 ∼+125	°C
	Mounting Torque	Mounting (M6)	Recommended Value 2.5~3.9 (25~40)	4.7 (48)	N·m (kgf·cm)
		Terminal (M5)	Recommended Value 1.5~2.5 (15~25)	2.7 (28)	
	Mass			170	g

■Electrical Characteristics

Symbol	Item	Conditions	Ratings	Unit
IDRM	Repetitive Peak Off-State Current, max.	at VDRM, single phase, half wave, Tj=150°C	15	mA
IRRM	Repetitive Peak Reverse Current, max.	at VDRM, single phase, half wave, Tj=150°C	15	mA
VTM	Peak On-State Voltage, max.	On-State Current 310A, Tj=25 °C Inst. measurement	1.20	V
IGT / VGT	Gate Trigger Current/Voltage, max.	Tj=25°C, Iτ=1A, VD=6V	150/2	mA/V
VgD	Non-Trigger Gate, Voltage. min.	Tj=150°C, VD=1∕2VDRM	0.25	V
tgt	Turn On Time, max.	IT=100A, IG=200mA, Tj=25 °C, VD= $\frac{1}{2}$ VDRM, dIg/dt=1A/ μ S	10	μS
dv/dt	Critical Rate of Rise of Off-State Voltage, min.	Tj=150°C, V□=2/₃VDRM, Exponential wave.	50	V/μs
Ін	Holding Current, typ.	Tj=25℃	70	mA
Rth (j-c)	Thermal Impedance, max.	Junction to case (1/3 Module)	0.3	°C/W

PWB100A







